









SBVS314B - MARCH 2018-REVISED OCTOBER 2018

TPS7A10

TPS7A10 300-mA, Low V_{IN}, Low V_{OUT,} Ultra-Low Dropout Regulator

Features

- Ultra-Low Input Voltage Range: 0.75 V to 3.3 V
- Ultra-Low Dropout for Minimum Power Loss:
 - 70 mV (Maximum) at 300 mA (V_{OUT} > 1.0 V), YKA Package
- Low Quiescent Current:
 - $V_{IN} I_{O} = 1.6 \mu A$ (Typical)
 - $V_{BIAS} I_Q = 6 \mu A$ (Typical)
- 1.5% Accuracy over Load, Line, and Temperature
- High PSRR: 60 dB at 1 kHz
- Available in Fixed-Output Voltages:
 - 0.5 V to 3.0 V (in 50-mV Steps)
- V_{BIAS} Range: 1.7 V to 5.5 V
- Packages:
 - 0.74-mm x 1.09-mm WCSP-5
 - 1.50-mm × 1.50-mm WSON-6
- Built-In Soft Start With Monotonic VOLT Rise
- Active Output Discharge

Applications

- Smart Watch, Fitness Trackers
- Wireless Headphones and Earbuds
- Camera Modules
- **Smart Phones and Tablets**
- Portable Medical Devices

3 Description

The TPS7A10 is an ultra-small, low quiescent current, low-dropout regulator (LDO) that can source 300 mA with an outstanding ac performance (load and line transient responses). This device has an input range of 0.75 V to 3.3 V, and output range of 0.5 V to 3.0 V with a very high accuracy of 1.5% over load, line and temperature. This performance is ideal for powering the lower core voltages of the modern MCUs and analog sensors.

The main power path is through V_{IN} and can be connected to a power supply as low as 70 mV above the output voltage. This device supports very low input voltages with the use of an additional VBIAS rail that is used to power the internal circuitry of the LDO. Both V_{IN} and V_{BIAS} consume very low quiescent current of 1.6 µA and 6 µA, respectively. The low IQ and ultra-low dropout features helps in increasing the efficiency of the solution in the power-sensitive applications. For example, VIN can be an output of a high-efficiency, DC/DC step-down regulator, and the V_{BIAS} pin can be connected to a rechargeable battery.

The TPS7A10 is equipped with an active pull-down circuit to quickly discharge the output when disabled, and provides a known start-up state.

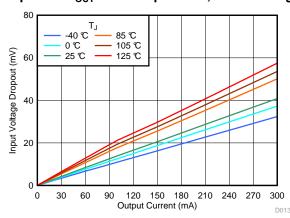
The TPS7A10 is available in an ultra-small, 5-pin DSBGA (YKA) package that makes the device suitable for space-constrained applications. The device is also available in a 6-pin WSON (DSE) package.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) | |
|-------------|-----------|--------------------------------------|--|
| | WSON (6) | 1.50 mm × 1.50 mm | |
| TPS7A10 | DSBGA (5) | 0.74 mm × 1.09 mm (0.35-mm pitch) | |

(1) For all available packages, see the package option addendum at the end of the data sheet.

Dropout vs I_{OUT} and Temperature, YKA Package



Typical Application Circuit

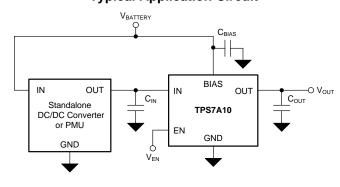




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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| CI | nanges from Revision A (June 2018) to Revision B | Page |
|----------|--|------|
| • | Added YKA Package to sub-bullet of Ultra-Low Dropout for Minimum Power Loss bullet in Features | 1 |
| • | Added last sentence to Description section | 1 |
| • | Changed WSON (DSE) package from Advanced Information to Production Data (active) | 1 |
| • | Added YKA Package to title of Dropout vs I _{OUT} and Temperature, YKA Package figure | 1 |
| • | Added YKA Package to captions of Output Accuracy Over Temperature, YKA Package and Output Accuracy Over Temperature, YKA Package figures | |
| • | Added Output Accuracy Over Temperature, DSE Package and Output Accuracy Over Temperature, DSE Package figures | |
| • | Added YKA Package to caption of Dropout vs I _{IOUT} and Temperature, YKA Package figure | |
| <u>.</u> | Added Dropout vs I _{IOUT} and Temperature, DSE Package figure | 8 |
| CI | nanges from Original (March 2018) to Revision A | Page |
| • | Changed from Advanced Information to Production Data (active) | 1 |



5 Pin Configuration and Functions



Pin Functions

| | PIN | | 1/0 | DESCRIPTION |
|------|-----|-----|-----|--|
| NAME | DSE | YKA | 1/0 | DESCRIPTION |
| IN | 6 | A1 | I | Input pin. For best transient response and to minimize input impedance, use the recommended or larger value ceramic capacitor from IN to ground. as listed in the <i>Recommended Operation Conditions</i> . Place the input capacitor as close as possible to input of the device. |
| OUT | 1 | А3 | 0 | Regulated output pin. A capacitor is required from OUT to ground for stability. For best transient response, use larger than the minimum recommended value ceramic capacitor. Follow the recommended capacitor value as listed in the <i>Recommended Operation Conditions</i> . Place the output capacitor as close as possible to output of the device. |
| GND | 5 | B2 | _ | Ground pin. This pin must be connected to ground. |
| BIAS | 4 | C1 | I | BIAS pin. This pin enables the use of low-input voltage, low-output voltage conditions, (LILO). For best response, use the recommended or larger value ceramic capacitor from BIAS to ground as listed in the <i>Recommended Operation Conditions</i> . Place the bias capacitor as close as possible to input of the device. |
| EN | 3 | C3 | I | Enable pin. Driving this pin to logic high enables the device. Driving this pin to logic low disables the device. If enable functionality is not required, this pin must be connected to IN or BIAS; however, connecting EN to IN is only acceptable if the V _{IN} voltage is greater than 0.9 V. |



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range unless otherwise noted. (1)

| | | MIN | MAX | UNIT |
|-------------|--|----------------------|----------------------|------|
| | Supply, V _{IN} | -0.3 | 3.6 | |
| Voltage | Enable, V _{EN} | -0.3 | 6.0 | \/ |
| voltage | Bias, V _{BIAS} | -0.3 | 6.0 | V |
| | Output, V _{OUT} | -0.3 | $V_{IN} + 0.3^{(2)}$ | |
| Current | Maximum output current | Internally limited A | | Α |
| Tomporeture | Operating junction temperature, T _J | -40 | 150 | °C |
| Temperature | Storage temperature, T _{stg} | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| \/ | Flactroatatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1) | ±1000 | \/ |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 (2) | ±500 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted).

| | | MIN | NOM | MAX | UNIT |
|----------------------|--------------------------------|------|-----|-----|------|
| V _{IN} | Input voltage | 0.75 | | 3.3 | V |
| V _{BIAS} | Bias voltage | 1.7 | | 5.5 | V |
| V _{OUT} | Output voltage | 0.5 | | 3.0 | V |
| I _{OUT} | Peak output current | 0 | | 300 | mA |
| C _{IN} | Input capacitor | 2.2 | | | μF |
| C _{BIAS} | Bias capacitor | | 0.1 | | μF |
| C _{OUT} (1) | Output capacitor | 2.2 | | 22 | μF |
| TJ | Operating junction temperature | -40 | | 125 | °C |

⁽¹⁾ Maximum ESR must be lower than 250 m Ω

6.4 Thermal Information

| | | TPS' | 7A10 | |
|------------------------|--|------------|------------|------|
| | THERMAL METRIC ⁽¹⁾ | DSE (WSON) | YKA (WSCP) | UNIT |
| | | 6 PINS | 5 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 188.8 | 169.4 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 82.9 | 1.1 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 101.0 | 55.4 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 6.6 | 1.7 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 100.4 | 55.6 | °C/W |
| R _θ JC(bot) | Junction-to-case (bottom) thermal resistance | N/A | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

⁽²⁾ The absolute maximum rating is 3.6 or $(V_{IN} + 0.3)$, whichever is less.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics

over T $_J$ = -40°C to +125°C, V $_{IN}$ = V $_{OUT(NOM)}$ + 0.5 V, V $_{BIAS}$ = V $_{OUT(NOM)}$ + 1.4 V, I $_{OUT}$ = 1 mA, V $_{EN}$ = 1.0 V, C $_{IN}$ = 2.2 μ F, C $_{OUT}$ = 2.2 μ F, and C $_{BIAS}$ = 0.1 μ F (unless otherwise noted); all typical values are at T $_J$ = 25°C .

| F | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT | |
|--------------------------------------|--|---|-------|-------|------|------|--|
| | Nominal Accuracy | T _J = 25°C | -0.5 | | 0.5 | | |
| | | -20°C ≤ T _J ≤ 85, DSE package $V_{OUT(NOM)}$ + 0.5 V ≤ V_{IN} ≤ 3.3 V, $V_{OUT(NOM)}$ + 1.4 V ≤ V_{BIAS} ≤ 5.5 V, 1 mA ≤ I_{OUT} ≤ 300 mA | -1.25 | | 1.25 | | |
| | Accuracy over temperature | -40°C ≤ T _J ≤ 85, YKA package $V_{OUT(NOM)}$ + 0.5 V ≤ V_{IN} ≤ 3.3 V, $V_{OUT(NOM)}$ + 1.4 V ≤ V_{BIAS} ≤ 5.5 V, 1 mA ≤ I_{OUT} ≤ 300 mA | -1.25 | | 1.25 | % | |
| | | -40 °C \leq T _J \leq 125, DSE and YKA package V _{OUT(NOM)} + 0.5 V \leq V _{IN} \leq 3.3 V, V _{OUT(NOM)} + 1.4 V \leq V _{BIAS} \leq 5.5 V, 1 mA \leq I _{OUT} \leq 300 mA | -1.5 | | 1.5 | | |
| ΔV_{OUT} / ΔV_{IN} | V _{IN} line regulation | $V_{OUT(NOM)} + 0.5 \text{ V} \le V_{IN} \le 3.3 \text{ V}$ | | 0.001 | | %/V | |
| ΔV_{OUT} / ΔV_{BIAS} | V _{BIAS} line regulation | $V_{OUT(NOM)} + 1.4 \text{ V} \le V_{BIAS} \le 5.5 \text{ V}$ | | 0.03 | | %/V | |
| ΔV_{OUT} / ΔI_{OUT} | Load regulation | 0.1 mA ≤ I _{OUT} ≤ 300 mA | | 0.2 | | %/A | |
| | Diag nin gurrant | $T_J = 25$ °C, $I_{OUT} = 0$ mA | 3 | 6 | 8 | | |
| $I_{Q(BIAS)}$ | | -40°C < T _J < 85°C, I _{OUT} = 0 mA | | | 11 | | |
| | Bias pin current | I _{OUT} = 0 mA | | | 14 | μA | |
| | | I _{OUT} = 300 mA | | | 60 | | |
| | Input pin current ⁽¹⁾ | T _J = 25°C, I _{OUT} = 0 mA | | 1.6 | 2.1 | μΑ | |
| | | -40°C < T _J < 85°C, I _{OUT} = 0 mA | | | 2.3 | | |
| I _{Q(IN)} | | I _{OUT} = 0 mA | | | 2.6 | | |
| | | I _{OUT} = 300 mA | | | 9 | | |
| | V shutdawa awaa at | -40°C < T _J < 85°C, V _{IN} = 3.3 V, V _{BIAS} = 5.5 V, V _{EN} ≤ 0.4 V | | | 400 | A | |
| ISHDN(BIAS) | V _{BIAS} shutdown current | -40°C < T _J < 125°C, V _{IN} = 3.3 V, V _{BIAS} = 5.5 V, V _{EN} ≤ 0.4 V | | | 1200 | nA | |
| la carronn | V _{IN} shutdown current | -40°C < T _J < 85 °C, V _{IN} = 3.3 V, V _{BIAS} = 5.5 V, V _{EN} ≤ 0.4 V | | | 1 | μA | |
| ISHDN(IN) | V _{IN} shatdown current | -40°C < T _J < 125°C, V _{IN} = 3.3 V, V _{BIAS} = 5.5 V, V _{EN} ≤ 0.4 V | | | 3 | μΛ | |
| la. | Output current limit | $V_{OUT} = 0.9 \times V_{OUT(NOM)}$, YKA package | 325 | 450 | 600 | mA | |
| I _{CL} | Output current minit | $V_{OUT} = 0.9 \times V_{OUT(NOM)}$, DSE package | 350 | 450 | 625 | mA | |
| I _{sc} | Short circuit current limit | V _{OUT} = 0 V | | 150 | | mA | |
| Vacan | V _{IN} dropout voltage (2) | $V_{\rm IN} = V_{\rm OUT(NOM)} - 0.1 \ \rm V, \ I_{\rm OUT} = 300 \ mA, \ \rm YKA \ package$ | | 40 | 70 | mV | |
| V _{DO(IN)} | VIN dropout voltage // | $V_{\text{IN}} = V_{\text{OUT(NOM)}} - 0.1 \text{ V, } I_{\text{OUT}} = 300 \text{ mA,}$ DSE package | | 55 | 90 | IIIV | |
| V | V dropout voltage (2) | I _{OUT} = 300 mA | | 0.85 | 1.05 | V | |
| $V_{DO(BIAS)}$ | V _{BIAS} dropout voltage ⁽²⁾ | I _{OUT} = 150 mA | | 0.75 | 0.95 | V | |

⁽¹⁾ This current flowing from V_{IN} to GND. (2) Dropout is not measured for V_{OUT} < 1.0 V



Electrical Characteristics (continued)

over T $_J$ = -40°C to +125°C, V $_{IN}$ = V $_{OUT(NOM)}$ + 0.5 V, V $_{BIAS}$ = V $_{OUT(NOM)}$ + 1.4 V, I $_{OUT}$ = 1 mA, V $_{EN}$ = 1.0 V, C $_{IN}$ = 2.2 μ F, C $_{OUT}$ = 2.2 μ F, and C $_{BIAS}$ = 0.1 μ F (unless otherwise noted); all typical values are at T $_J$ = 25°C .

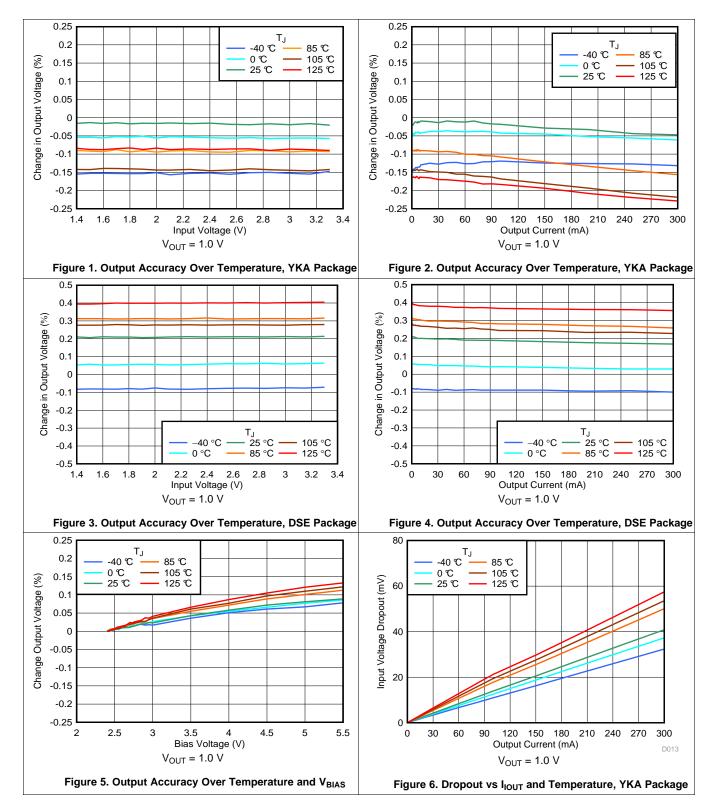
| P | ARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------------|--|---|------|------|------|---------------|
| | | f = 1 kHz, V _{OUT} = 1.1 V, I _{OUT} = 50 mA | | 60 | | |
| V . BODB | V _{IN} power-supply rejection | f = 100 kHz, V _{OUT} = 1.1 V, I _{OUT} = 50 mA | | 36 | | dB |
| V _{IN} PSRR | ratio | f = 1 MHz, $V_{OUT} = 1.1 \text{ V}, I_{OUT} = 50 \text{ mA}$ | | 32 | | uБ |
| | | f = 1.5 MHz, V _{OUT} = 1.1 V, I _{OUT} = 50 mA | | 35 | | |
| | | f = 1 kHz, $V_{OUT} = 1.1 \text{ V}, I_{OUT} = 300 \text{ mA}$ | | 60 | | |
| V _{BIAS} PSRR | AS PSRR V _{BIAS} power-supply rejection ratio | f = 100 kHz, V _{OUT} = 1.1 V, I _{OUT} = 300 mA | | 40 | | dB |
| | | f = 1 MHz, $V_{OUT} = 1.1 \text{ V}, I_{OUT} = 300 \text{ mA}$ | | 35 | | |
| V _n | Output voltage noise | Bandwidth = 10 Hz to 100 kHz, V _{OUT} = 1.0 V, I _{OUT} = 50 mA | | 93.9 | | μV_{RMS} |
| V | Bias supply UVLO | V _{BIAS} rising | 1.46 | 1.54 | 1.63 | V |
| $V_{UVLO(BIAS)}$ | bias supply UVLO | V _{BIAS} falling | 1.35 | 1.44 | 1.55 | V |
| V _{UVLO_HYST(BIAS)} | Bias supply hysteresis | V _{BIAS} hysteresis | | 80 | | mV |
| W | Inner to complete LIV/LO | V _{IN} rising | 645 | 675 | 710 | mV |
| $V_{UVLO(IN)}$ | Input supply UVLO | V _{IN} falling | 565 | 600 | 640 | mV |
| V _{UVLO_HYST(IN)} | Input supply hysteresis | V _{IN} hysteresis | | 75 | | mV |
| t _{STR} | Start-up time (3) | | | 525 | 1200 | μs |
| V _{HI(EN)} | EN pin logic high voltage | | 0.9 | | | V |
| V _{LO(EN)} | EN pin logic low voltage | | | | 0.4 | V |
| I _{EN} | EN pin current | EN = 5.5 V | | 10 | | nA |
| R _{PULLDOWN} | Pulldown resistor | V _{BIAS} = 3.3 V, P version only | | 120 | | Ω |
| | Thermal shutdown | Shutdown, temperature rising | | 160 | | ۰. |
| T _{SD} | temperature | Reset, temperature falling | | 145 | | °C |

⁽³⁾ Startup time = time from EN assertion to $0.95 \times V_{OUT(NOM)}$.



6.6 Typical Characteristics

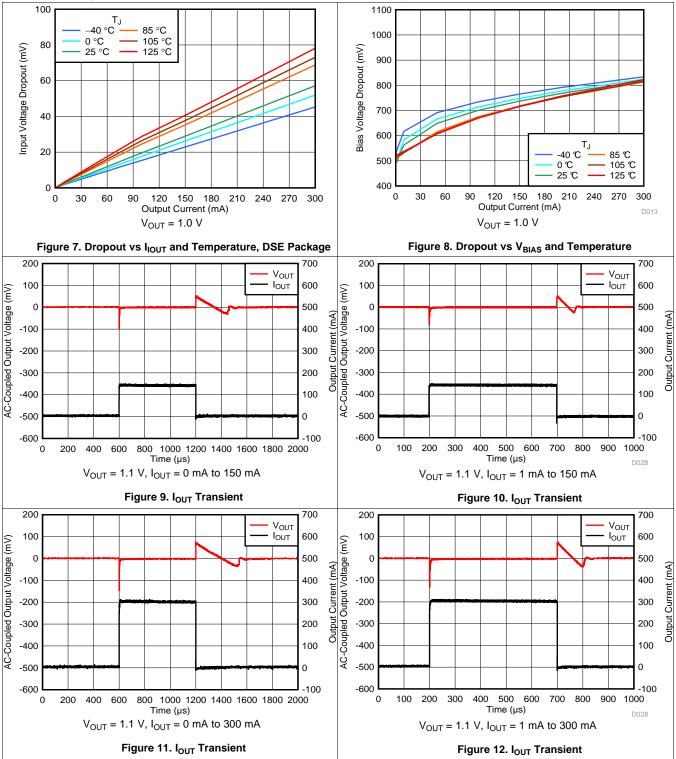
at $T_J = -40$ °C to +125 °C, $V_{IN} = V_{OUT(NOM)} + 0.5$ V, $V_{BIAS} = V_{OUT(NOM)} + 1.4$ V, $I_{OUT} = 1$ mA, $V_{EN} = V_{IN}$, $C_{IN} = 2.2$ μF , $C_{OUT} = 2.2$ μF , and $C_{BIAS} = 0.1$ μF (unless otherwise noted); typical values are at $T_J = 25$ °C



TEXAS INSTRUMENTS

Typical Characteristics (continued)

at T $_J$ = -40 °C to +125 °C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V, V_{BIAS} = $V_{OUT(NOM)}$ + 1.4 V, I_{OUT} = 1 mA, V_{EN} = V_{IN} , C_{IN} = 2.2 μ F, C_{OUT} = 2.2 μ F, and C_{BIAS} = 0.1 μ F (unless otherwise noted); typical values are at T_J = 25°C



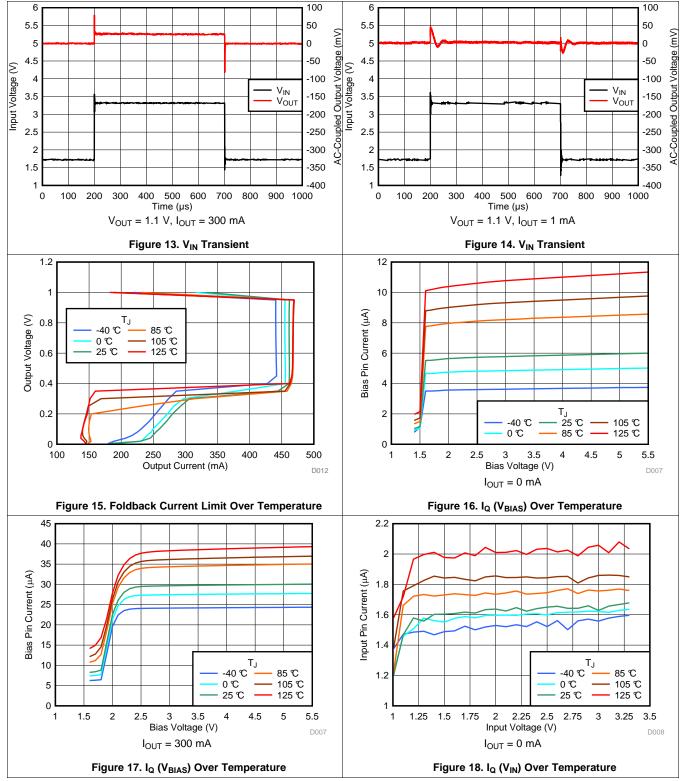
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Typical Characteristics (continued)

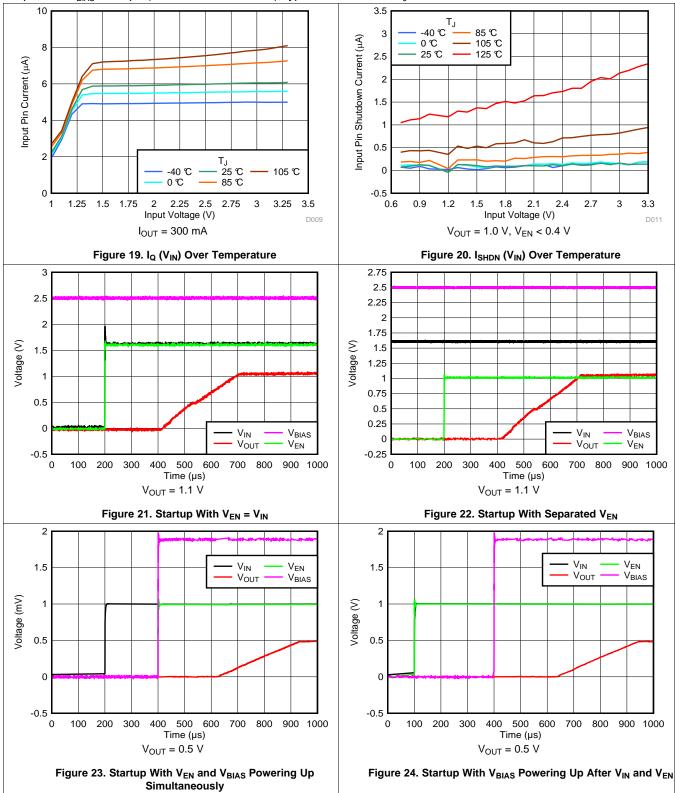
at T $_J$ = -40 °C to +125 °C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V, V_{BIAS} = $V_{OUT(NOM)}$ + 1.4 V, I_{OUT} = 1 mA, V_{EN} = V_{IN} , C_{IN} = 2.2 μ F, C_{OUT} = 2.2 μ F, and C_{BIAS} = 0.1 μ F (unless otherwise noted); typical values are at T_J = 25°C



TEXAS INSTRUMENTS

Typical Characteristics (continued)

at T $_J$ = -40 °C to +125 °C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V, V_{BIAS} = $V_{OUT(NOM)}$ + 1.4 V, I_{OUT} = 1 mA, V_{EN} = V_{IN} , C_{IN} = 2.2 μ F, C_{OUT} = 2.2 μ F, and C_{BIAS} = 0.1 μ F (unless otherwise noted); typical values are at T_J = 25°C



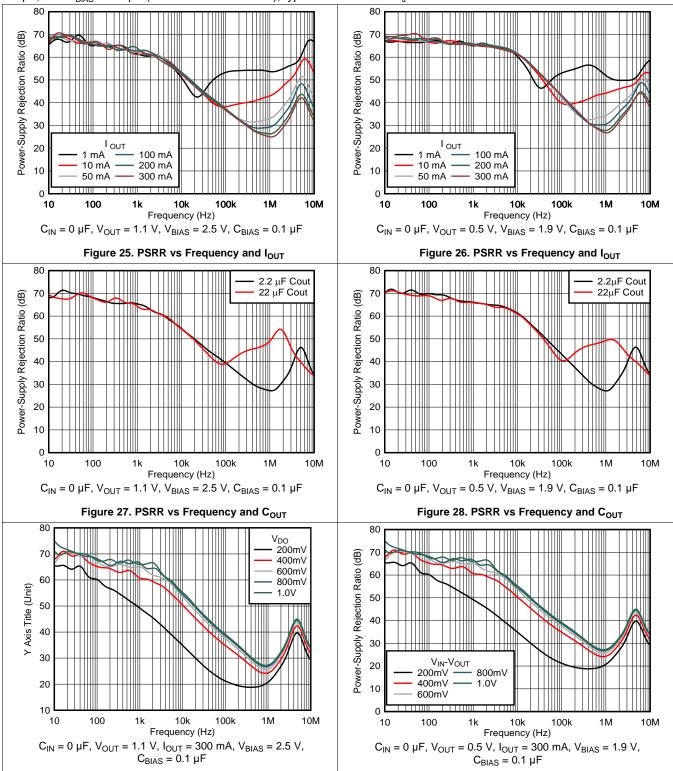
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Typical Characteristics (continued)

at T $_J$ = -40 °C to +125 °C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V, V_{BIAS} = $V_{OUT(NOM)}$ + 1.4 V, I_{OUT} = 1 mA, V_{EN} = V_{IN} , C_{IN} = 2.2 μ F, C_{OUT} = 2.2 μ F, and C_{BIAS} = 0.1 μ F (unless otherwise noted); typical values are at T_J = 25°C



Product Folder Links: TPS7A10

Figure 29. PSRR vs Frequency and V_{DO}

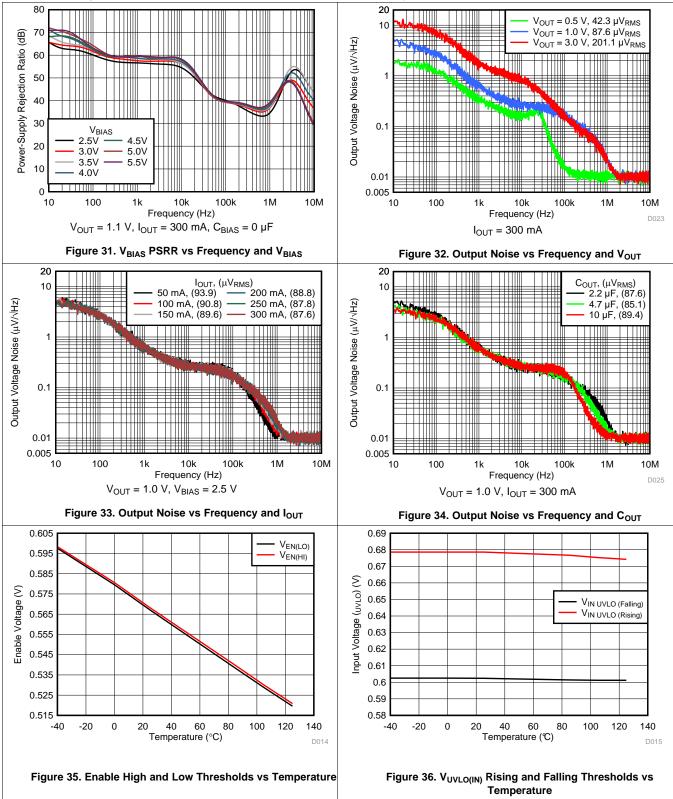
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Figure 30. PSRR vs Frequency and V_{DO}

TEXAS INSTRUMENTS

Typical Characteristics (continued)

at T_J = -40 °C to +125 °C, V_{IN} = V_{OUT(NOM)}+ 0.5 V, V_{BIAS} = V_{OUT(NOM)} + 1.4 V, I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 2.2 μ F, C_{OUT} = 2.2 μ F, and C_{BIAS} = 0.1 μ F (unless otherwise noted); typical values are at T_J = 25°C



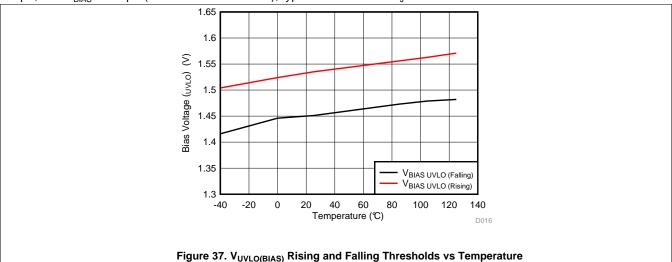
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Typical Characteristics (continued)

at T_J = -40 °C to +125 °C, V_{IN} = V_{OUT(NOM)}+ 0.5 V, V_{BIAS} = V_{OUT(NOM)} + 1.4 V, I_{OUT} = 1 mA, V_{EN} = V_{IN}, C_{IN} = 2.2 μ F, C_{OUT} = 2.2 μ F, and C_{BIAS} = 0.1 μ F (unless otherwise noted); typical values are at T_J = 25°C



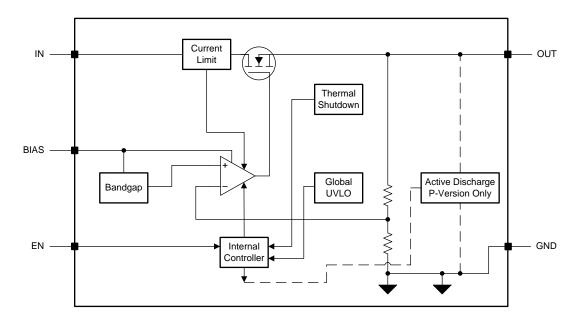


7 Detailed Description

7.1 Overview

The TPS7A10 is a low input, ultra-low dropout, and low quiescent current linear regulator that is optimized for excellent transient performance. These characteristics make the device ideal for most battery-powered applications. The implementation of the BIAS pin on the TPS7A10 vastly improves efficiency of low-voltage output applications by allowing the use of a preregulated, low-voltage input supply that offers sub-band-gap output voltages. The high power-supply rejection ratio (PSRR), low noise, low ground pin current, and ultra-small packaging make this device suitable for ultra-portable applications. This device also offers high output voltage accuracy of 1.5% over the recommended junction temperature range.

7.2 Functional Block Diagram



Product Folder Links: TPS7A10

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7.3 Feature Description

7.3.1 Excellent Transient Response

The TPS7A10 responds quickly to a transient on the input supply (line transient) or the output current (load transient) that results from the device high input impedance and low output impedance across frequency. This same capability also means that the device has a high power-supply rejection ratio (PSRR) and low internal noise floor (e_n). The low-dropout regulator (LDO) approximates an ideal power supply in ac (small-signal) and dc (large-signal) conditions.

The choice of external component values optimizes the small- and large-signal response; see the *Input and Output Capacitor Requirements* section for proper selection.

7.3.2 Global Undervoltage Lockout (UVLO)

The TPS7A10 uses two undervoltage lockout (UVLO) circuits: one on the BIAS pin and one on the IN pin to prevent the device from turning on before both V_{BIAS} and V_{IN} rise above their lockout voltages. The two UVLO signals are connected internally through an AND gate, as shown in Figure 38. This internal connection allows the device to be turned off when either rail is below its lockout voltage.

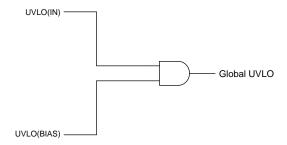


Figure 38. Global UVLO circuit

7.3.3 Active Discharge

The active discharge option (P version only) have internal pulldown MOSFET that connects a $120-\Omega$ resistor to ground when the device is disabled in order to actively discharge the output voltage. The active discharge circuit is activated by driving the enable pin to logic low to disable the device, or when the device is in thermal shutdown.

The discharge time after disabling the device depends on the output capacitance (C_{OUT}) and the load resistance (R_L) in parallel with the 120- Ω pulldown resistor. Equation 1 calculates the discharge time constant:

$$\tau = \frac{120 \cdot R_L}{120 + R_L} \cdot C_{OUT} \tag{1}$$

Do not rely on the active discharge circuit for discharging a large amount of output capacitance after the input supply collapses because reverse current can possibly flow from the output to the input. This reverse current flow can cause damage to the device. Limit reverse current to no more than 5% of the device-rated current.

7.3.4 Enable

The enable pin for this device is active high. The output of the device is turned on when the enable pin voltage is greater than the EN pin logic high voltage, and the output of the device is turned off when the enable pin voltage is less than the EN pin voltage logic low.

The EN pin can be tied to the IN pin, the BIAS pin, or can be driven separately to enable and disable the device; however, connecting the EN pin to the IN pin is only acceptable if the V_{IN} voltage is greater than 0.9 V.



Feature Description (continued)

7.3.5 Sequencing Requirement

The V_{IN} , V_{BIAS} , and V_{EN} voltages can be sequenced in any order without causing damage to the device. The start up is always monotonic regardless of the sequencing order or the ramp rates of IN, BIAS, and EN pins. For optimum device performance, have V_{BIAS} present before enabling the device in any sequence order between V_{IN} and V_{EN} because the device internal circuitry is powered off the V_{BIAS} , refer to *Recommended Operating Conditions* for proper voltage ranges of V_{IN} , V_{BIAS} , and V_{EN} .

7.3.6 Internal Foldback Current Limit

The internal foldback current limit circuit is used to protect the LDO against high-load current faults or shorting events. The foldback mechanism lowers the current limit as the output voltage decreases, and limits power dissipation during short-circuit events while still allowing for the device to operate at the rated output current; see Figure 15.

For example, when V_{OUT} is 90% of $V_{OUT(nom)}$, the current limit is I_{CL} (typical); however, if V_{OUT} is forced to 0 V, the current limit is I_{SC} (typical).

In many LDOs, the foldback current limit can prevent start up into a constant-current load or a negatively-biased output. A *brick-wall* current limit is when there is an abrupt current stop after the current limit is reached. The foldback mechanism for this device goes into a *brick-wall* current limit when $V_{OUT} > 500$ mV (typical), thus limiting current to I_{CL} (typical). When V_{OUT} is approximately 0 V, current is limited to I_{SC} (typical) in order to provide normal start up into a variety of loads.

Thermal shutdown can activate during a current-limit event because of the high power dissipation typically found in these conditions. To provide proper operation of the current limit, minimize the inductances to the input and load. Continuous operation in current limit is not recommended.

7.3.7 Thermal Shutdown

The device contains a thermal shutdown protection circuit to disable the device when the thermal junction temperature (T_J) of the main pass-FET rises to the thermal shutdown temperature (T_{SD}) for shutdown listed in the *Electrical Characteristics*. Thermal shutdown hysteresis makes sure that the LDO resets again (turns on) when the temperature falls to the T_{SD} for reset.

The thermal time constant of the semiconductor die is fairly short, and thus the device may cycle on and off when thermal shutdown is reached until the power dissipation is reduced.

For reliable operation, limit the junction temperature to a maximum of 125°C. Operation above 125°C causes the device to exceed the operational specifications. Although the internal protection circuitry of the device is designed to protect against thermal overload conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above a junction temperature of 125°C reduces long-term reliability.

A fast start up when T_J > the T_{SD} for reset causes the device thermal shutdown to assert at T_{SD} for reset, and prevents the device from turning on until the junction temperature is reduced below T_{SD} for reset.



7.4 Device Functional Modes

The device has the following modes of operation:

- Normal operation: The device regulates to the nominal output voltage.
- Dropout operation: The pass element operates as a resistor and the output voltage is set as V_{IN} V_{DO}.
- Disabled: The output of the device is disabled and the discharge circuit is activated.

Table 1 shows the conditions that lead to the different modes of operation.

Table 1. Device Functional Mode Comparison

| OPERATING MODE | PARAMETER | | | | | | |
|--|---|---|-----------------------|--------------------|---|--|--|
| OPERATING WODE | V _{IN} | V _{BIAS} | V _{EN} | I _{out} | T _J | | |
| Normal mode | $V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$ | V _{BIAS} > V _{OUT} + 1.05 V | $V_{EN} > V_{HI(EN)}$ | $I_{OUT} < I_{CL}$ | T _J < T _{SD} for shutdown | | |
| Dropout mode | $V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$ | $V_{BIAS} < V_{OUT} + 1.05 V$ | $V_{EN} > V_{HI(EN)}$ | $I_{OUT} < I_{CL}$ | $T_J < T_{SD}$ for shutdown | | |
| Disabled mode (any true condition disables the device) | V _{IN} < V _{UVLO(IN)} | V _{BIAS} < V _{BIAS(UVLO)} | $V_{EN} < V_{LO(EN)}$ | - | $T_J > T_{SD}$ for shutdown | | |

7.4.1 Normal Mode

The device regulates the output to the nominal output voltage when all normal mode conditions in Table 1 are met.

7.4.2 Dropout Mode

The device is not in regulation, and the output voltage tracks the input voltage minus the voltage drop across the pass element of the device. In this mode, PSRR and the noise performance of the device are significantly degraded.

7.4.3 Disable Mode

In this mode, the pass element is turned off, the internal circuits are shut down, and the output voltage is actively discharged to ground by an internal resistor.



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

Successfully implementing an LDO in an application depends on the application requirements. This section discusses key device features and the best implementation to achieve a reliable design.

8.1.1 Recommended Capacitor Types

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input, output, and BIAS pins. Multilayer ceramic capacitors are the industry standard for these types of applications, but must be used with good judgment. Ceramic capacitors that use X7R-, X5R-, and COG-rated dielectric materials provide relatively good capacitive stability across temperature. Avoid Y5V-rated capacitors because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, ceramic capacitance varies with operating voltage and temperature. As a rule of thumb, assume that effective capacitance decreases by as much as 50%. The input, output, and bias capacitors recommended in the *Recommended Operating Conditions* table account for an effective capacitance of approximately 50% of the nominal value.

8.1.2 Input and Output Capacitor Requirements

A minimum 2.2- μ F ceramic capacitor at the input is required for stability, A minimum 2.2- μ F ceramic capacitor with a maximum ESR value of less than 250 m Ω at the output is also required for stability. The input capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. A higher-value input capacitor may be necessary if large, fast rise-time load or line transients are anticipated, or if the device is located several inches from the input power source. Dynamic performance of the device is improved with the use of an output capacitor larger than the minimum value specified in the *Recommended Operating Conditions* table.

Although a bias capacitor is not required, connect a 0.1-µF ceramic capacitor from BIAS to GND for best analog design practice. This capacitor counteracts reactive bias sources if the source impedance is not sufficiently low.

Place the input, output, and bias capacitors as close as possible to the device to minimize traces parasitics.



Application Information (continued)

8.1.3 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current while output voltage regulation is maintained. See Figure 9, Figure 10, Figure 11, and Figure 12 for typical load transient response. There are two key transitions during a load transient response: the transition from a light to a heavy load, and the transition from a heavy to a light load. The regions in Figure 39 are broken down as described in this section. Regions A, E, and H are where the output voltage is in steady-state operation.

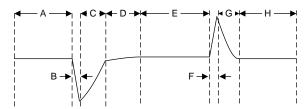


Figure 39. Load Transient Waveform

During transitions from a light load to a heavy load:

- The initial voltage dip is a result of the depletion of the output capacitor charge and parasitic impedance to the output capacitor (region B)
- Recovery from the dip results from the LDO increasing the sourcing current, and leads to output voltage regulation (region C)

During transitions from a heavy load to a light load:

- The initial voltage rise results from the LDO sourcing a large current, and leads to the output capacitor charge to increase (region F)
- Recovery from the rise results from the LDO decreasing the sourcing current in combination with the load discharging the output capacitor (region G)

A larger output capacitance reduces the peaks during a load transient, but slows down the response time of the device. A larger dc load also reduces the peaks because the amplitude of the transition is lowered, and a higher current discharge path is provided for the output capacitor.

8.1.4 Dropout Voltage

Generally, dropout voltage refers to the minimum voltage difference between the input and output voltage ($V_{DO} = V_{IN} - V_{OUT}$) that is required for regulation. When $V_{IN} - V_{OUT}$ drops below the required V_{DO} for the given load current, the device functions as a resistive switch and does not regulate output voltage. Dropout voltage is proportional to the output current because the device is operating as a resistive switch.

Dropout voltage is affected by the drive strength of the pass-element gate. This drive strength is nonlinear with respect to V_{IN} on this device.

8.1.5 Behavior During Transition From Dropout Into Regulation

Some applications may have transients that place this device into dropout, especially when this device can be powered from a battery with relatively high ESR. The load transient saturates the output stage of the error amplifier when the pass element is driven fully on, making the pass element function like a resistor from V_{IN} to V_{OUT} . The error amplifier response time to this load transient is limited because the error amplifier must first recover from saturation and then place the pass element back into active mode. During this time, V_{OUT} overshoots because the pass element is functioning as a resistor from V_{IN} to V_{OUT} .

When V_{IN} ramps up slowly for start-up, the slow ramp-up voltage may place the device in dropout. As with many other LDOs, the output can overshoot on recovery from this condition. However, this condition is easily avoided through the use of the enable signal.

If operating under these conditions, apply a higher dc load or increase the output capacitance to reduce the overshoot. These solutions provide a path to dissipate the excess charge.



Application Information (continued)

8.1.6 Undervoltage Lockout Circuit Operation

The V_{IN} UVLO circuit makes sure that the device remains disabled before the input supply reaches the minimum operational voltage range. The V_{IN} UVLO circuit also makes sure that the device shuts down when the input supply collapses. Similarly, the V_{BIAS} UVLO circuit makes sure that the device stays disabled before the bias supply reaches the minimum operational voltage range. The V_{BIAS} UVLO circuit also makes sure that the device shuts down when the bias supply collapses.

Figure 40 depicts the UVLO circuit response to various input or bias voltage events. This figure can be separated into the following parts:

- Region A: The device does not start until the input or bias voltage reaches the UVLO rising threshold.
- Region B: Normal operation, regulating device
- Region C: Brownout event above the UVLO falling threshold (UVLO rising threshold UVLO hysteresis). The output may fall out of regulation, but the device is still enabled.
- Region D: Normal operation, regulating device
- Region E: Brownout event below the UVLO falling threshold. The device is disabled in most cases, and the
 output falls as a result of the load and active discharge circuit. The device is re-enabled when the UVLO
 rising threshold is reached, and a normal start-up follows.
- Region F: Normal operation followed by the input or bias falling to the UVLO falling threshold
- Region G: The device is disabled as the input or bias voltages fall below the UVLO falling threshold to 0 V. The output falls as a result of the load and active discharge circuit.

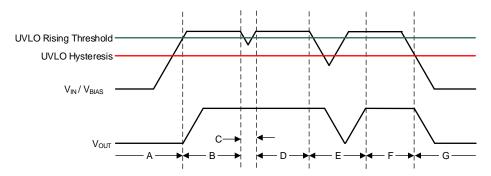


Figure 40. Typical V_{IN} or V_{BIAS} UVLO Circuit Operation

8.1.7 Power Dissipation (P_D)

Circuit reliability demands that proper consideration be given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses.

Equation 2 calculates the maximum allowable power dissipation for the device in a given package:

$$P_{D-MAX} = [(T_J - T_A) / R_{\theta JA}]$$
(2)

Equation 3 represents the actual power being dissipated in the device:

$$P_{D} = (I_{GND} + I_{OUT}) \times (V_{IN} - V_{OUT})$$
(3)

Power dissipation can be minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the TPS7A10 allows for maximum efficiency across a wide range of output voltages.

The main heat conduction path for the device depends on the ambient temperature and the thermal resistance across the various interfaces between the die junction and ambient air.



Application Information (continued)

The maximum power dissipation determines the maximum allowable junction temperature (T_J) for the device. According to Equation 4, maximum power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance $(R_{\theta JA})$ of the combined PCB and device package and the temperature of the ambient air (T_A) . The equation is rearranged in Equation 5 for output current.

$$T_{J} = T_{A} + (R_{\theta JA} \times P_{D}) \tag{4}$$

$$I_{OUT} = (T_J - T_A) / [R_{\theta JA} \times (V_{IN} - V_{OUT})]$$
(5)

Unfortunately, this thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The $R_{\theta JA}$ recorded in the *Thermal Information* table is determined by the JEDEC standard, PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance.

8.1.7.1 Estimating Junction Temperature

The JEDEC standard recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics $(\Psi_{JT}$ and $\Psi_{JB})$ are used in accordance with Equation 6 and are given in the *Thermal Information* table.

$$\Psi_{JT}$$
: $T_J = T_T + \Psi_{JT} \times P_D$ and Ψ_{JB} : $T_J = T_B + \Psi_{JB} \times P_D$

where:

- P_D is the power dissipated as explained in Equation 3
- T_T is the temperature at the center-top of the device package
- T_B is the PCB surface temperature measured 1 mm from the device package and centered on the package edge

8.1.7.2 Recommended Area for Continuous Operation

The operational area of an LDO is limited by the dropout voltage, output current, junction temperature, and input voltage. The recommended area for continuous operation for a linear regulator is shown in Figure 41, and can be separated into the following regions:

- Dropout voltage limits the minimum differential voltage between the input and the output (V_{IN} V_{OUT}) at a
 given output current level.
- The rated output currents limits the maximum recommended output current level. Exceeding this rating causes the device to fall out of specification.
- The rated junction temperature limits the maximum junction temperature of the device. Exceeding this rating
 causes the device to fall out of specification and reduces long-term reliability.
 - Equation 5 provides the shape of the slope. The slope is nonlinear because the maximum rated junction temperature of the LDO is controlled by the power dissipation across the LDO, thus when V_{IN} - V_{OUT} increases, the output current must decrease.
- The rated input voltage range governs both the minimum and maximum of V_{IN} V_{OUT}.

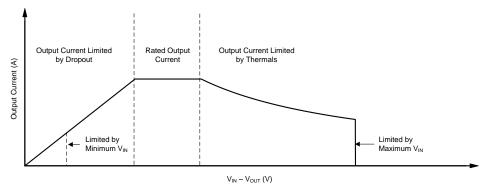


Figure 41. Region Description of Continuous Operation Regime



8.2 Typical Application

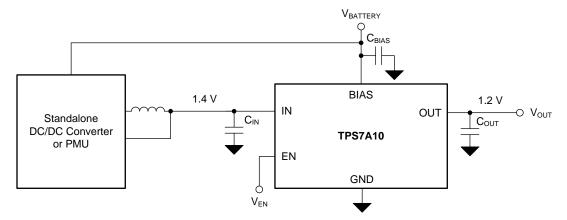


Figure 42. Supplying a Clean DC Voltage

8.2.1 Design Requirements

Table 2 summarizes the design requirements for Figure 42.

 DESIGN PARAMETER
 EXAMPLE VALUE

 V_{IN}
 1.4 V

 V_{BIAS}
 2.7 V

 V_{OUT}
 1.2 V

 I_{OUT}
 10-mA typical, 300-mA peak

 Maximum ambient temperature
 65°C

Table 2. Design Parameters

8.2.2 Detailed Design Procedure

For this design example, the 1.2-V, fixed-version TPS7A1012 device is selected. Use a $4.7-\mu F$ input capacitor to minimize transient currents drawn from the DC/DC convertor. Use a $4.7-\mu F$ output capacitor for optimized load transient response. The dropout voltage (V_{DO}) is kept within the TPS7A10 dropout voltage specification for the 1.2-V output voltage option inorder to keep the device in regulation under all load and temperature conditions for this design. The high-PSRR and low-noise measurements for this design example are given in the *Thermal Dissipation* section.

8.2.2.1 Input Current

During normal operation, the input current to the LDO is approximately equal to the output current of the LDO. During startup, the input current is higher as a result of the inrush current charging the output capacitor. Use Equation 7 to calculate the current through the input.

$$I_{OUT(t)} = \left[\frac{C_{OUT} \times dV_{OUT}(t)}{dt}\right] + \left[\frac{V_{OUT}(t)}{R_{LOAD}}\right]$$

where:

- V_{OUT}(t) is the instantaneous output voltage of the turnon ramp
- dV_{OUT}(t) / dt is the slope of the V_{OUT} ramp
- R_{LOAD} is the resistive load impedance

(7)



8.2.2.2 Thermal Dissipation

The junction temperature can be determined using the junction-to-ambient thermal resistance ($R_{\theta JA}$) and the total power dissipation (P_D). Use Equation 8 to calculate the power dissipation. As Equation 9 shows, multiply P_D by $R_{\theta JA}$ and add the ambient temperature (T_A) to calculate the junction temperature (T_A).

$$P_{D} = (I_{GND} + I_{OUT}) \times (V_{IN} - V_{OUT})$$
(8)

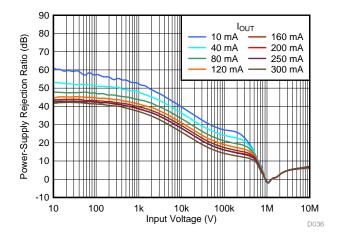
$$T_{J} = R_{\theta, JA} \times P_{D} + T_{A} \tag{9}$$

If the $(T_{J(MAX)})$ value does not exceed 125°C, use Equation 10 to calculate the maximum ambient temperature. Equation 11 calculates the maximum ambient temperature with a value of 99.59°C.

$$T_{A(MAX)} = T_{J(MAX)} - R_{\theta JA} \times P_{D}$$
 (10)

$$T_{A(MAX)} = 125^{\circ}C - 169.4 \times (1.4 \text{ V} - 1.2 \text{ V}) \times (0.3 \text{ A}) = 114.84^{\circ}C$$
 (11)

8.2.3 Application Curve



$$V_{IN} = 1.4 \text{ V}, V_{OUT} = 1.2 \text{ V}, V_{BIAS} = 2.7 \text{ V},$$

 $C_{IN} = 4.7 \mu\text{F}, C_{OUT} = 4.7 \mu\text{F}, C_{BIAS} = 0.1 \mu\text{F}$

Figure 43. PSRR vs Frequency and I_{OUT}

9 Power Supply Recommendations

This device is designed to operate from an input supply voltage range of 0.75 V to 3.3 V, and a bias supply voltage range of 1.7 V to 5.5 V. The input and bias supplies must be well regulated and free of spurious noise. To make sure that the output voltage is well regulated and dynamic performance is optimum, the input supply must be at least $V_{OUT(nom)} + 0.5 V$ and $V_{BIAS} = V_{OUT(nom)} + 1.05 V$.

10 Layout

10.1 Layout Guidelines

For correct printed circuit board (PCB) layout, follow these guidelines:

- Place input, output, and bias capacitors as close to the device as possible.
- Use copper planes for device connections to optimize thermal performance.
- Place thermal vias around the device to distribute heat.

10.2 Layout Examples

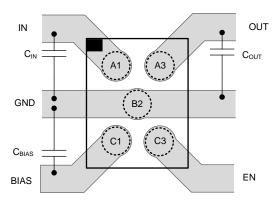


Figure 44. Recommended Layout for the YKA Package

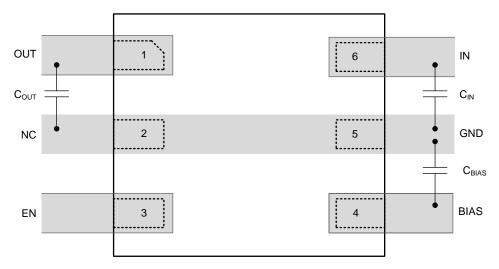


Figure 45. Recommended Layout for the DSE Package



11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

11.1.1.1 Evaluation Module

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS7A10. The *TPS7A10EVM* can be requested at the Texas Instruments website through the product folders or purchased directly from the TI eStore.

11.1.1.2 Spice Model

Spice models for this device are available through the for the TPS7A10 product folder under the *Tool and Software* tab.

11.1.2 Device Nomenclature

Table 3. Device Nomenclature (1)(2)

| PRODUCT | V _{OUT} |
|------------------|--|
| TPS7A10xx(x)yyyz | xx(x) is the nominal output voltage. For output voltages with a resolution of 50 mV, two digits are used in the ordering number; otherwise, three digits are used (for example, 28 = 2.8 V; 125 = 1.25 V). yyy is the package designator. z is the package quantity. R is for reel, T is for tape. |

For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on www.ti.com.

11.2 Documentation Support

11.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, TPS7A10EVM-004 Evaluation Module user's guide
- Texas Instruments, Using New Thermal Metrics application report
- Texas Instruments, AN-1112 DSBGA Wafer Level Chip Scale Package application report

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.5 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

⁽²⁾ Output voltages from 0.5 V to 3.0 V in 50-mV increments are available. Contact the factory for details and availability.



11.6 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 10-Nov-2025

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|-----------------|-----------------------|-----------------|-------------------------------|----------------------------|--------------|------------------|
| TPS7A1006PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | EF |
| TPS7A1006PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | EF |
| TPS7A1006PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | EF |
| TPS7A1006PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | EF |
| TPS7A1006PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | T |
| TPS7A1006PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | T |
| TPS7A1008PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | E2 |
| TPS7A1008PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | E2 |
| TPS7A1008PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | E2 |
| TPS7A1008PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | E2 |
| TPS7A1008PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | А |
| TPS7A1008PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | А |
| TPS7A10105PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DZ |
| TPS7A10105PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DZ |
| TPS7A10105PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DZ |
| TPS7A10105PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DZ |
| TPS7A10105PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | С |
| TPS7A10105PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | С |
| TPS7A1010PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | E1 |
| TPS7A1010PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | E1 |
| TPS7A1010PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | E1 |
| TPS7A1010PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | E1 |
| TPS7A1010PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | В |
| TPS7A1010PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | В |
| TPS7A1011PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DX |
| TPS7A1011PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DX |
| TPS7A1011PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DX |
| TPS7A1011PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DX |
| TPS7A1011PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | D |





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| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|-----------------|-----------------------|-----------------|-------------------------------|----------------------------|--------------|------------------|
| TPS7A1011PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | D |
| TPS7A1012PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DW |
| TPS7A1012PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DW |
| TPS7A1012PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DW |
| TPS7A1012PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DW |
| TPS7A1012PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | E |
| TPS7A1012PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | E |
| TPS7A1015PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DV |
| TPS7A1015PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DV |
| TPS7A1015PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DV |
| TPS7A1015PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DV |
| TPS7A1015PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | F |
| TPS7A1015PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | F |
| TPS7A1018PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DU |
| TPS7A1018PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DU |
| TPS7A1018PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DU |
| TPS7A1018PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DU |
| TPS7A1018PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | G |
| TPS7A1018PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | G |
| TPS7A1025PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DT |
| TPS7A1025PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DT |
| TPS7A1025PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DT |
| TPS7A1025PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DT |
| TPS7A1025PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | Н |
| TPS7A1025PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | Н |
| TPS7A1028PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DS |
| TPS7A1028PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DS |
| TPS7A1028PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DS |
| TPS7A1028PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DS |
| TPS7A1028PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | I |
| TPS7A1028PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | I |

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| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking |
|-----------------------|--------|---------------|-----------------|-----------------------|------|-------------------------------|----------------------------|--------------|--------------|
| | (.) | (=) | | | (0) | (4) | (5) | | (0) |
| TPS7A1030PDSER | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DR |
| TPS7A1030PDSER.B | Active | Production | WSON (DSE) 6 | 3000 LARGE T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DR |
| TPS7A1030PDSET | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DR |
| TPS7A1030PDSET.B | Active | Production | WSON (DSE) 6 | 250 SMALL T&R | Yes | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | DR |
| TPS7A1030PYKAR | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | J |
| TPS7A1030PYKAR.A | Active | Production | DSBGA (YKA) 5 | 12000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 125 | J |

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No. RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

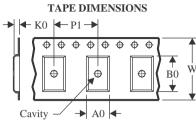
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



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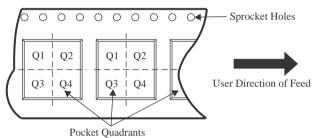
TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|-----------------|--------------------|------|-------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TPS7A1006PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1006PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1006PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1008PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1008PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1008PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A10105PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A10105PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A10105PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1010PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1010PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1010PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1011PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1011PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1011PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1012PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |



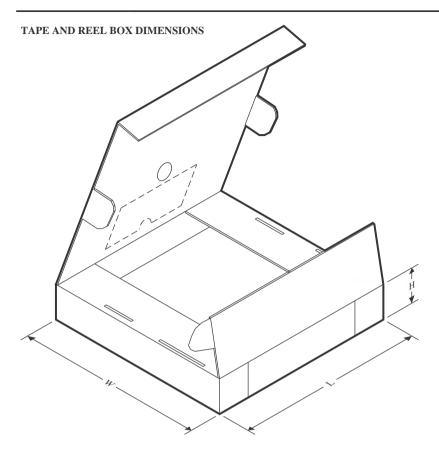
PACKAGE MATERIALS INFORMATION

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| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|------|-------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TPS7A1012PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1012PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1015PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1015PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1015PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1018PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1018PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1018PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1025PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1025PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1025PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1028PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1028PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1028PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |
| TPS7A1030PDSER | WSON | DSE | 6 | 3000 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1030PDSET | WSON | DSE | 6 | 250 | 180.0 | 8.4 | 1.83 | 1.83 | 0.89 | 4.0 | 8.0 | Q2 |
| TPS7A1030PYKAR | DSBGA | YKA | 5 | 12000 | 180.0 | 8.4 | 0.9 | 1.25 | 0.48 | 2.0 | 8.0 | Q1 |



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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|-------|-------------|------------|-------------|
| TPS7A1006PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1006PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1006PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A1008PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1008PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1008PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A10105PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A10105PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A10105PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A1010PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1010PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1010PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A1011PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1011PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1011PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A1012PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1012PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1012PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |



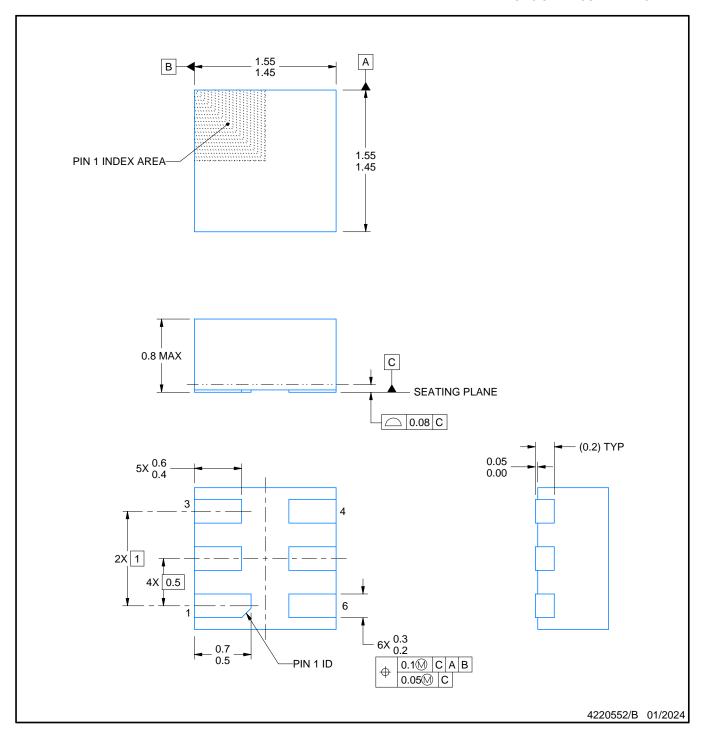
PACKAGE MATERIALS INFORMATION

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| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|-------|-------------|------------|-------------|
| TPS7A1015PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1015PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1015PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A1018PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1018PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1018PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A1025PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1025PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1025PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A1028PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1028PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1028PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |
| TPS7A1030PDSER | WSON | DSE | 6 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS7A1030PDSET | WSON | DSE | 6 | 250 | 183.0 | 183.0 | 20.0 |
| TPS7A1030PYKAR | DSBGA | YKA | 5 | 12000 | 182.0 | 182.0 | 20.0 |



PLASTIC SMALL OUTLINE - NO LEAD



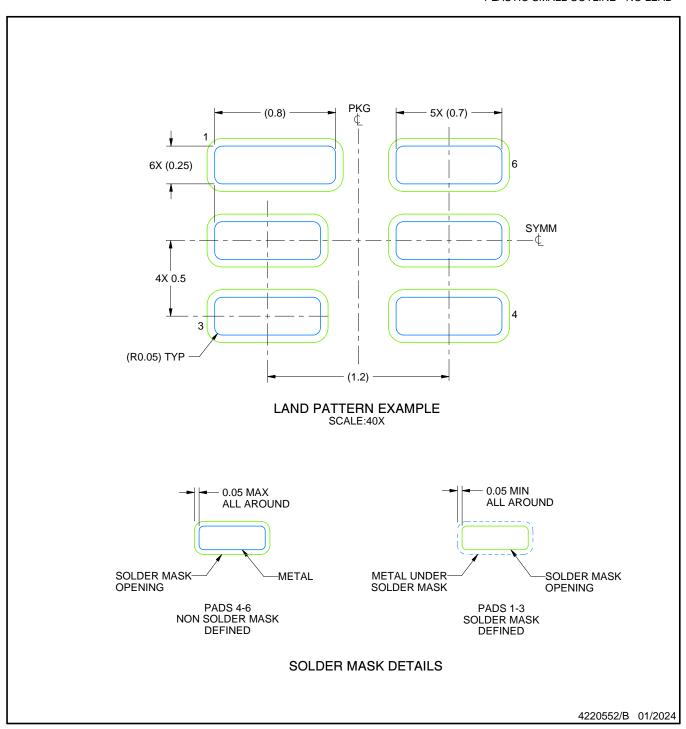
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.



PLASTIC SMALL OUTLINE - NO LEAD

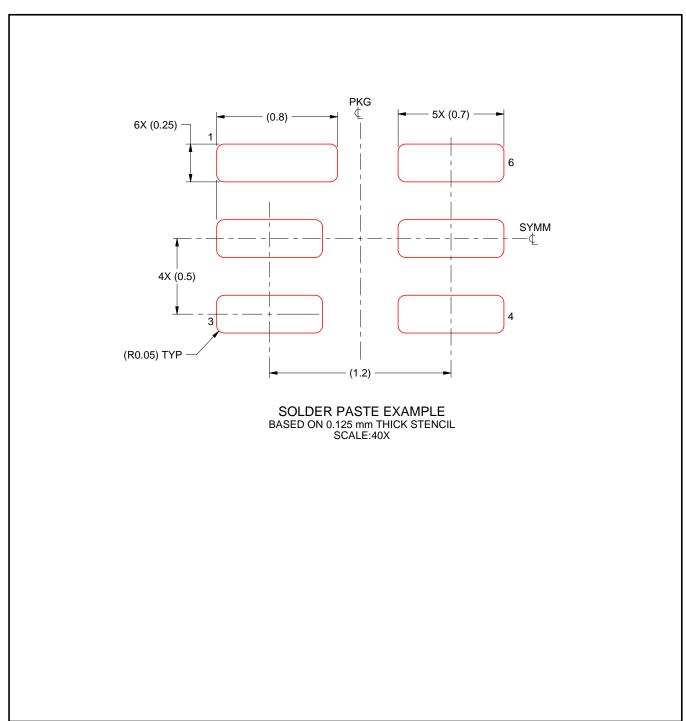


NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC SMALL OUTLINE - NO LEAD



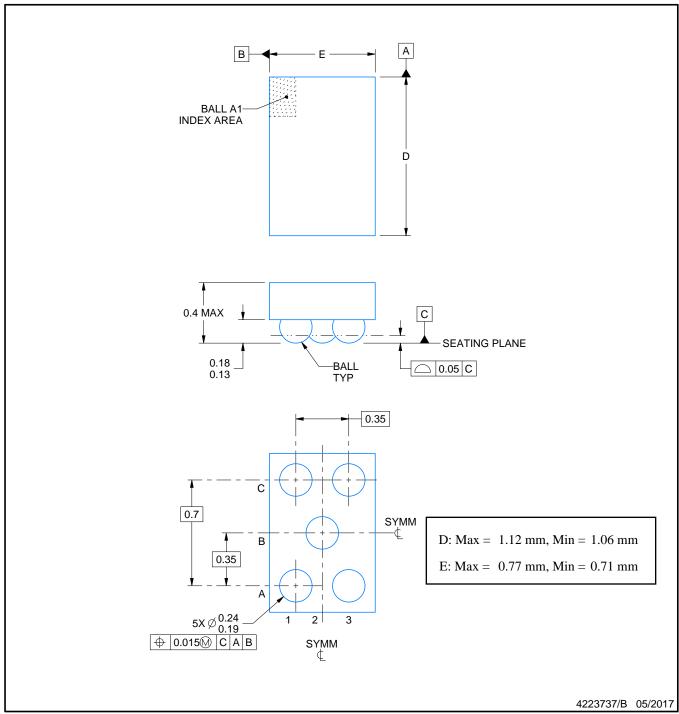
NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





DIE SIZE BALL GRID ARRAY



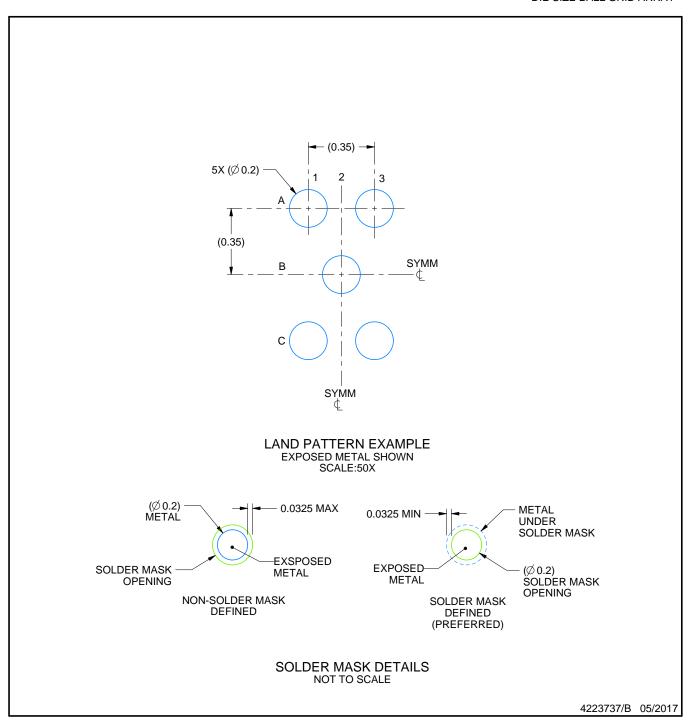
NOTES:

NanoFree Is a trademark of Texas Instruments.

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
- 3. NanoFree[™] package configuration.



DIE SIZE BALL GRID ARRAY

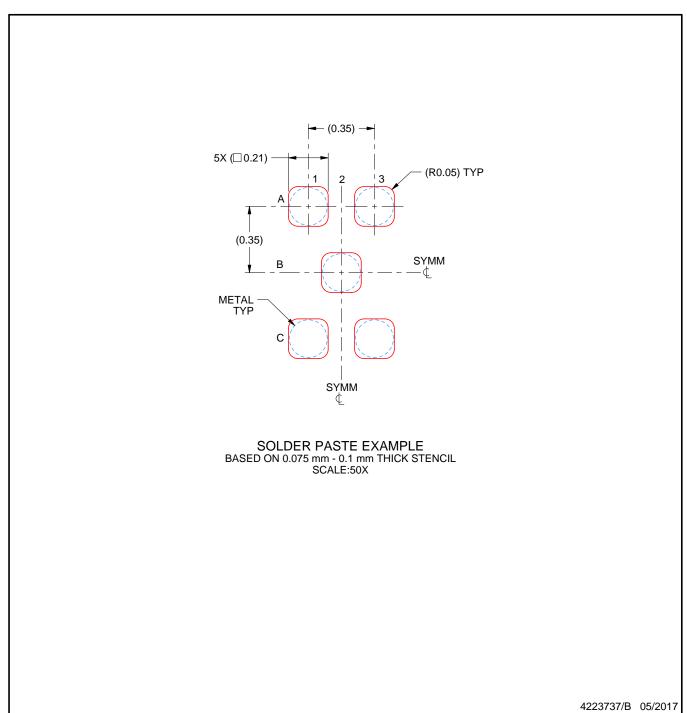


NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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